

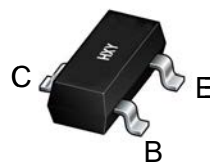


## Features

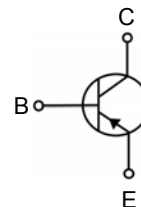
- Collector Current:  $I_C = -0.1A$
- Power Dissipation of 200mw

## Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HBC857C235	SOT-23	3G	3000



SOT-23



## Maxmim Ratings (Ta=25 unless otherwise noted)

Symbl	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-50	V
$V_{CEO}$	Collector-Emitter Voltage	-45	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current-Continuous	-0.1	A
$P_C$	Collector Power Dissipation	200	mW
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-55-150	°C

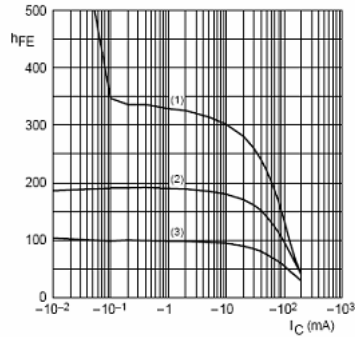


**Electrcal Charcteristics (Ta=25 unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	VCBO	IC= -10μA, IE=0	-50		V
Collector-emitter breakdown voltage	VCEO	IC= -10mA, IB=0	-45		V
Emitter-base breakdown voltage	VEBO	IE= -1μA, IC=0	-5		V
Collector cut-off current	ICBO	VCB= -45 V ,IE=0		-0.1	μA
Collector cut-off current	ICEO	VCE= -40 V , IB=0		-0.1	μA
Emitter cut-off current	IEBO	VEB= -5 V , IC=0		-0.1	μA
DC current gain	hFE	VCE= -5V, IC= -2mA	420	800	
Collector-emitter saturation voltage	VCE(sat)	IC=-100mA, IB= -5 mA		-0.5	V
Base-emitter saturation voltage	VBE(sat)	IC= -100mA, IB= -5mA		-1.1	V
Transition frequency	fT	VCE= -5 V, IC= -10mA f=100MHz	100		MHz
Collector capacitance	Cob	VCB=-10V, f=1MHz		4.5	pF

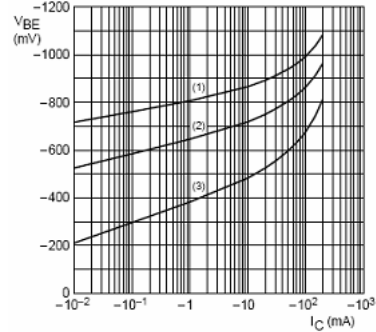


## Typical Characteristics



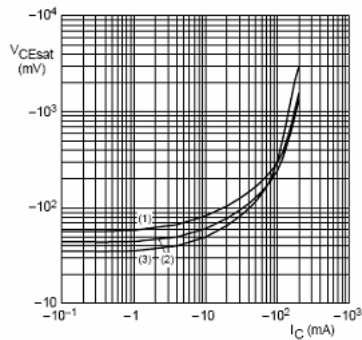
BC857A;  $V_{CE} = -5\text{ V}$ .  
(1)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .

Fig.2 DC current gain as a function of collector current; typical values.



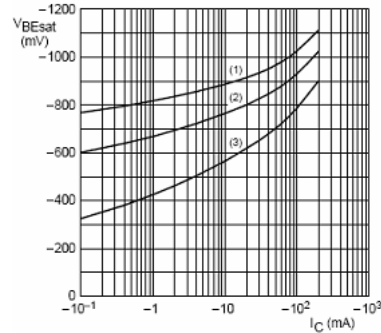
BC857A;  $V_{CE} = -5\text{ V}$ .  
(1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .

Fig.3 Base-emitter voltage as a function of collector current; typical values.



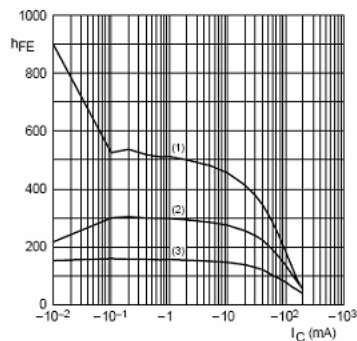
BC857A;  $I_C/I_B = 20$ .  
(1)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .

Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



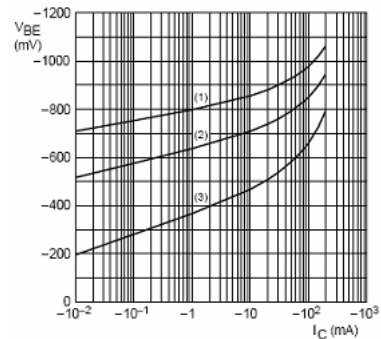
BC857A;  $I_C/I_B = 20$ .  
(1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.



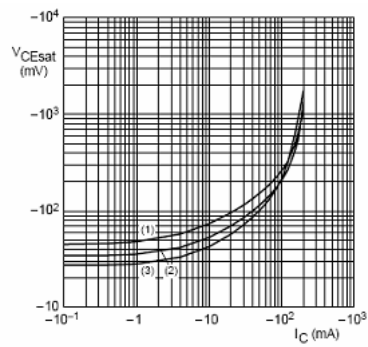
BC857B;  $V_{CE} = -5\text{ V}$ .  
(1)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .

Fig.6 DC current gain as a function of collector current; typical values.



BC857B;  $V_{CE} = -5\text{ V}$ .  
(1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .  
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
(3)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .

Fig.7 Base-emitter voltage as a function of collector current; typical values.



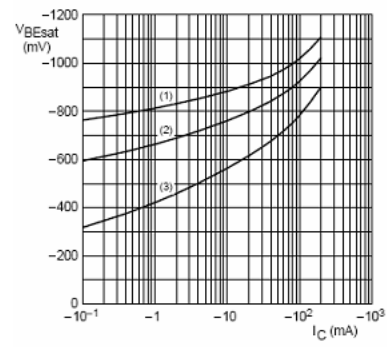
HBC857B;  $I_C/I_B = 20$ .

(1)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .

(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

(3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.



HBC857B;  $I_C/I_B = 20$ .

(1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$ .

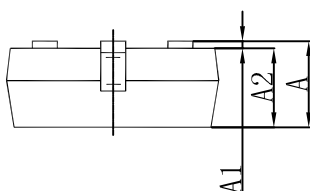
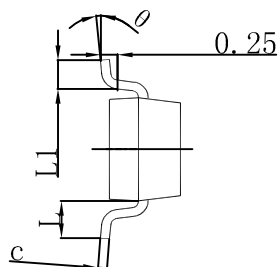
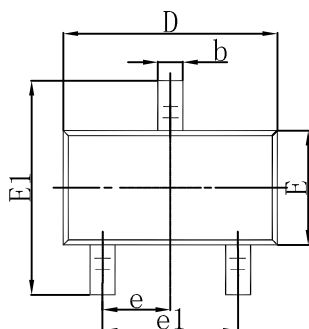
(2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

(3)  $T_{amb} = 150\text{ }^{\circ}\text{C}$ .

Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.

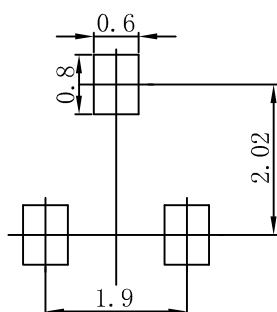


## Package Dimensions SOT-23



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## Suggested Pad Layout



Note:  
1. Controlling dimension: in millimeters.  
2. General tolerance:  $\pm 0.05\text{mm}$ .  
3. The pad layout is for reference purposes only.



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